

## N-Channel 150 V (D-S) Power MOSFET

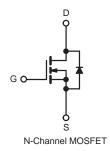
PRODUCT SUMMARY							
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (mΩ) (Typ.)	I <sub>D</sub> (A) <sup>a</sup>	Q <sub>g</sub> (Typ.)				
150	4.5 at V <sub>GS</sub> = 10 V	164	46 nC				

#### **FEATURES**

- DT-SGT Power MOSFET
- 100 % Rg and UIS tested
- Low On-Resistance

#### **APPLICATIONS**

- DC/DC in Telecoms and Inductrial
- · Synchronous Rectification in SMPS
- Hard Switching and High Speed Circuit



## TO-220 Pin Configuration Top View



ABSOLUTE MAXIMUM RATINGS (T <sub>C</sub> = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	LIMIT	UNIT				
Drain-Source Voltage	V <sub>DS</sub>	150	V				
Gate-Source Voltage	V <sub>GS</sub>	± 20					
Continuous Prois Compant /T 475 90\2	T <sub>C</sub> = 25 °C		164	А			
Continuous Drain Current (T <sub>J</sub> = 175 °C) <sup>a</sup>	T <sub>C</sub> = 100 °C	l <sub>D</sub>	116				
Pulsed Drain Current <sup>b</sup>	I <sub>DM</sub>	655					
Single Avalanche Energy	E <sub>AS</sub>	1796	mJ				
Maximum Dawar Dissination 6	T <sub>C</sub> = 25 °C	Р	333	W			
Maximum Power Dissipation <sup>c</sup>	T <sub>C</sub> = 100 °C	P <sub>D</sub>	167	VV			
Operating Junction and Storage Temperature Ra	T <sub>J</sub> , T <sub>stg</sub>	- 55 to +175	°C				

THERMAL RESISTANCE RATINGS						
PARAMETER	SYMBOL	LIMIT	UNIT			
Junction-to-Ambient (PCB Mount) <sup>d</sup>	R <sub>thJA</sub>	31	°C/W			
Junction-to-Case (Drain)	R <sub>thJC</sub>	0.45				

#### Notes

- a. Calculated continuous current based on maximum allowablejunction temperature.
- b. Repetitive rating; pulse width limited by max. junction temperature.
- c. Pd is based on max. junction temperature, using junction-case thermal resistance.
- d. The value of R<sub>8JA</sub> is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper,in a still air environment with Ta=25 °C.



SPECIFICATIONS (T <sub>C</sub> = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA	150	-	-	V	
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	2.5	-	4.5	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA	
Zero Gate Voltage Drain Current	1	V <sub>DS</sub> = 150 V, V <sub>GS</sub> = 0 V	-	-	1	μΑ	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 120 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 100 °C	-	-	100		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> ≥ 5 V, V <sub>GS</sub> = 10 V	164	-	-	Α	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A	-	4.5	5.4	mΩ	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 20 A	-	56	-	S	
Dynamic <sup>b</sup>				<u>.                                      </u>	<u> </u>		
Input Capacitance	C <sub>iss</sub>		-	3055	-	pF	
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 75 V, f = 1 MHz	-	768	-		
Reverse Transfer Capacitance	C <sub>rss</sub>		-	14	-		
Total Gate Charge <sup>c</sup>	Qg		-	46	-	nC	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>DS</sub> = 75 V,V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A	-	13.5	-		
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$		-	11.4	-		
Gate Resistance	$R_g$	f = 1 MHz	-	3	-	Ω	
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>		-	7.6	-		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 75 \text{ V}, I_D = 20 \text{ A}, R_g = 3 \Omega$	-	29	-	- ns	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	V <sub>GS</sub> = 10 V	-	32	-		
Fall Time <sup>c</sup>	t <sub>f</sub>		-	29	-		
Drain-Source Body Diode Ratings and	Characterist	tics <sup>b</sup> (T <sub>C</sub> = 25 °C)					
Continuous Source-Drain Diode Current	I <sub>S</sub>	T <sub>C</sub> = 25 °C	-	-	164	Α	
Pulsed Current	I <sub>SM</sub>		-	-	655	Α	
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = 1 A, V <sub>GS</sub> = 0 V	-	-	1.2	V	
Reverse Recovery Time	t <sub>rr</sub>			100	-	ns	
Reverse Recovery Charge	Q <sub>rr</sub>	$I_F = 20 \text{ A, di/dt} = 100 \text{ A/}\mu\text{s}$	-	399	-	nC	

#### **Notes**

- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those in dicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended pe riods may affect device reliability.

### TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)

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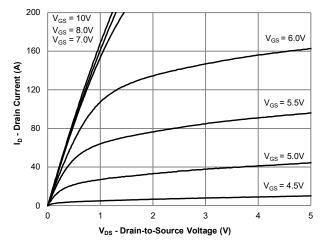


Figure 1: Output Characteristics

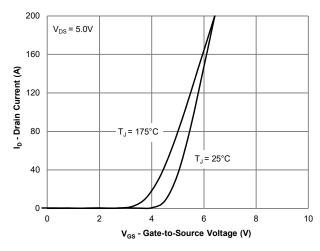


Figure 2: Transfer Characteristics

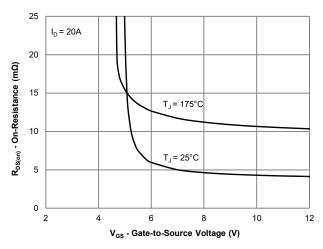


Figure 3: On-Resistance vs. Gate-Source Voltage

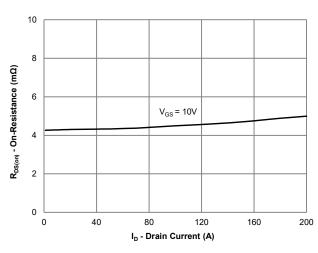


Figure 4: On-Resistance vs. Gate-Source Voltage

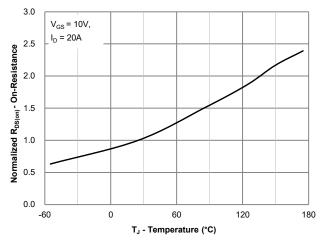


Figure 5: On-Resistance vs. Junction Temperature

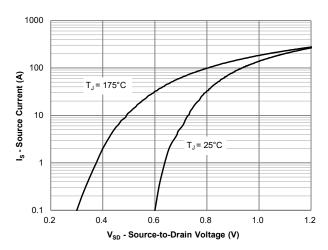


Figure 6: Source-Drain Diode Forward Voltage



### TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)

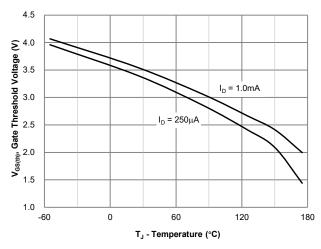


Figure 7: Gate Threshold Variation vs. Junction Temperature

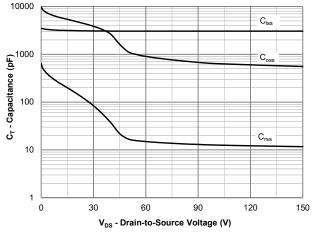


Figure 9: Capacitance Characteristics

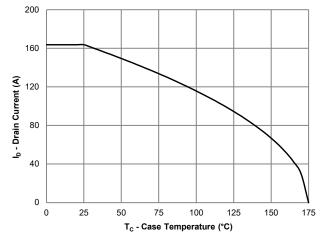


Figure 11: Current Derating

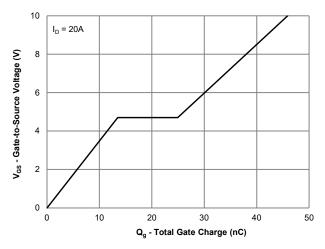


Figure 8: Gate Charge Characteristics

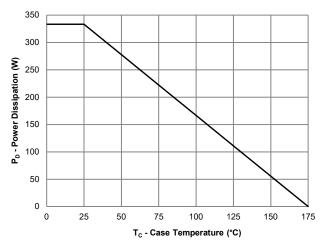


Figure 10: Power Derating

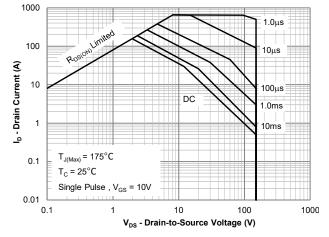


Figure 12: Safe Operating Area



TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)

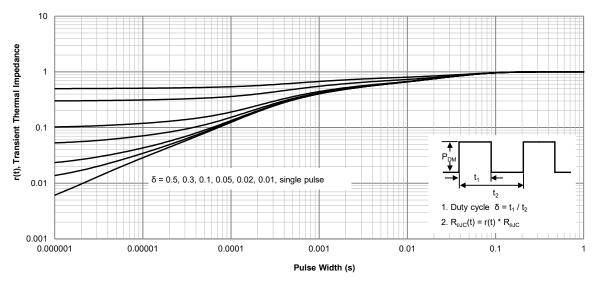
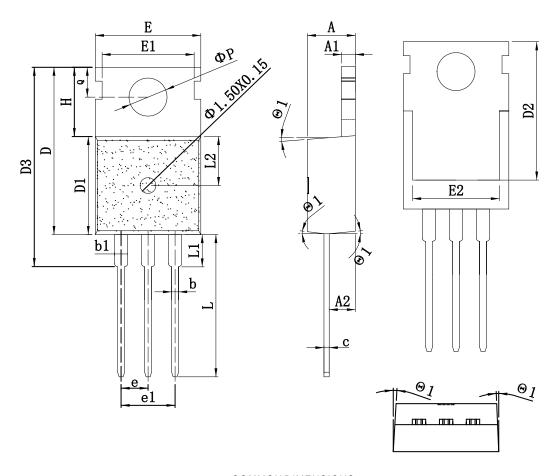


Figure 13: Normalized Maximum Transient Thermal Impedance



# **TO-220\_3L-A PACKAGE OUTLINE**

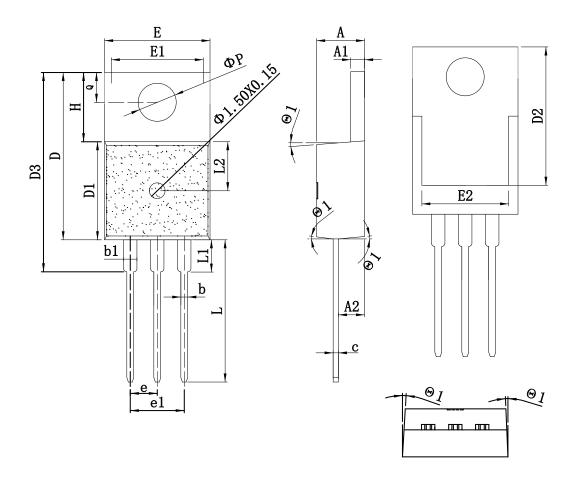


**COMMON DIMENSIONS** (UNITS OF MEASURE=mm)

SYMBOL	mm			CVMDOL	mm		
	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
Α	4.15	4.50	4.80	E1	8.25	8.70	9.15
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80
A2	2.10	2.40	2.65	е	2.38	2.54	2.74
b	0.65	0.80	1.00	e1	5.07 REF		
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90
С	0.35	0.50	0.65	L	12.75	13.28	13.70
D	14.25	15.75	16.15	L1	-	-	3.50
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00
D2	12.30	13.10	13.85	φР	3.40	3.65	3.85
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00
Е	8.68	10.02	11.00	θ	2°	-	7°



# **TO-220\_3L-B PACKAGE OUTLINE**



**COMMON DIMENSIONS** (UNITS OF MEASURE=mm)

0) (1.45.0)	mm			SYMBOL	mm		
SYMBOL	MIN	TYP	MAX	STIVIBUL	MIN	TYP	MAX
Α	4.15	4.50	4.80	E1	8.25	8.70	9.15
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80
A2	2.10	2.40	2.65	е	2.38	2.54	2.74
b	0.65	0.80	1.00	e1	5.08 REF		
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90
С	0.35	0.50	0.65	L	12.75	13.28	13.70
D	14.25	15.75	16.15	L1	-	-	3.50
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00
D2	12.30	13.10	13.85	φР	3.40	3.65	3.85
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00
Е	8.68	10.02	11.00	θ	2°	-	7°

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